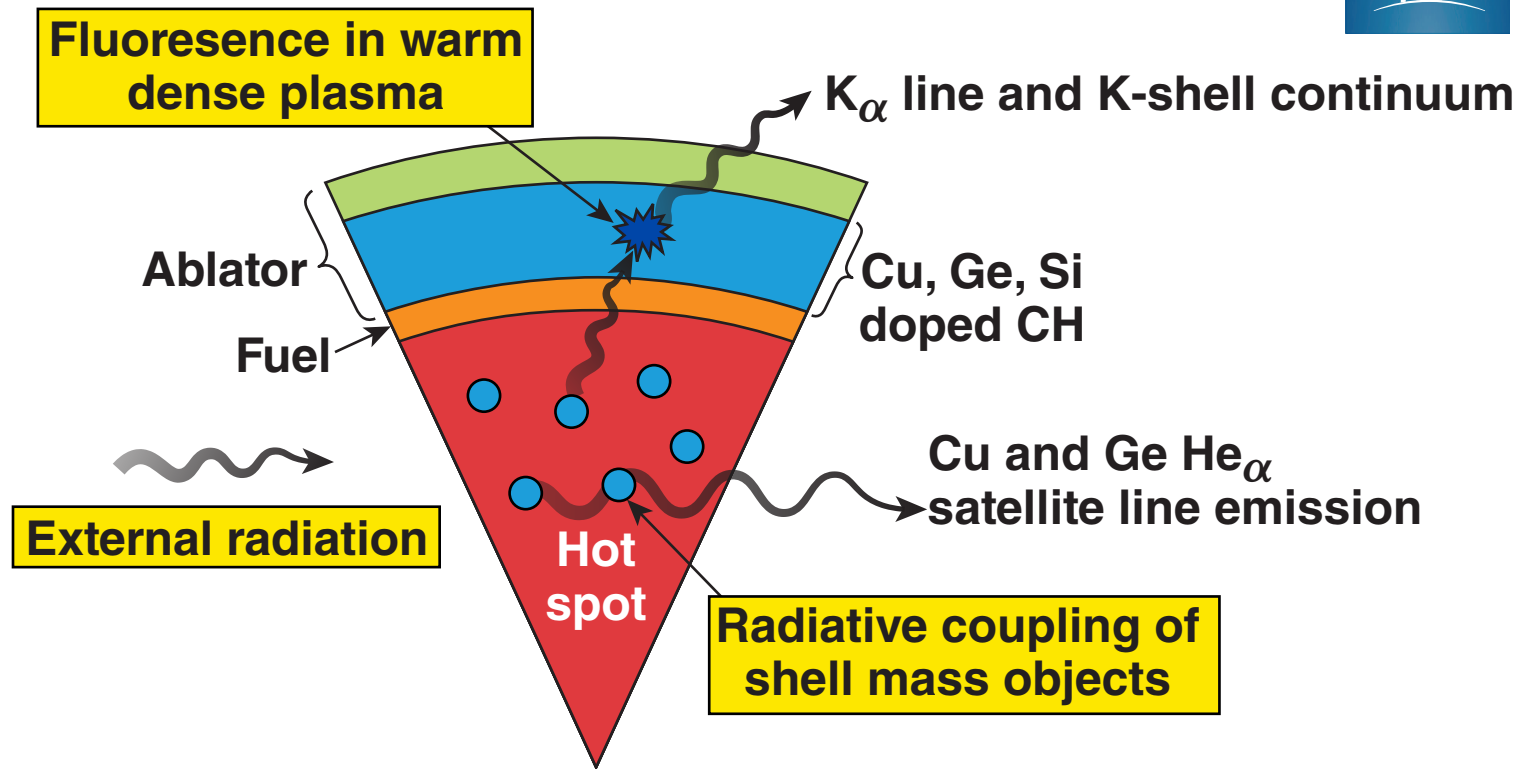


Spectroscopy of Mid-Z Shell Additives in Implosions at the National Ignition Facility



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Summary

Our NIF shell-dopant spectrum analysis takes several important issues into account



- The atomic-kinetic radiation-transport effects on He_α satellite line emission from dopants are treated adequately in a model representing the shell material mixed into the core as small, independently radiating objects
- External radiation within the hohlraum temperature range will not significantly affect the dopant ionization or line emission
- Cu and Ge cold-material values of K_α fluorescence efficiencies will be sufficiently accurate under warm dense shell conditions

Collaborators



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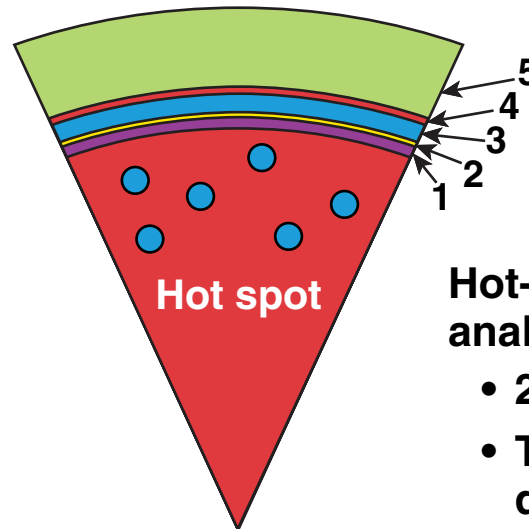
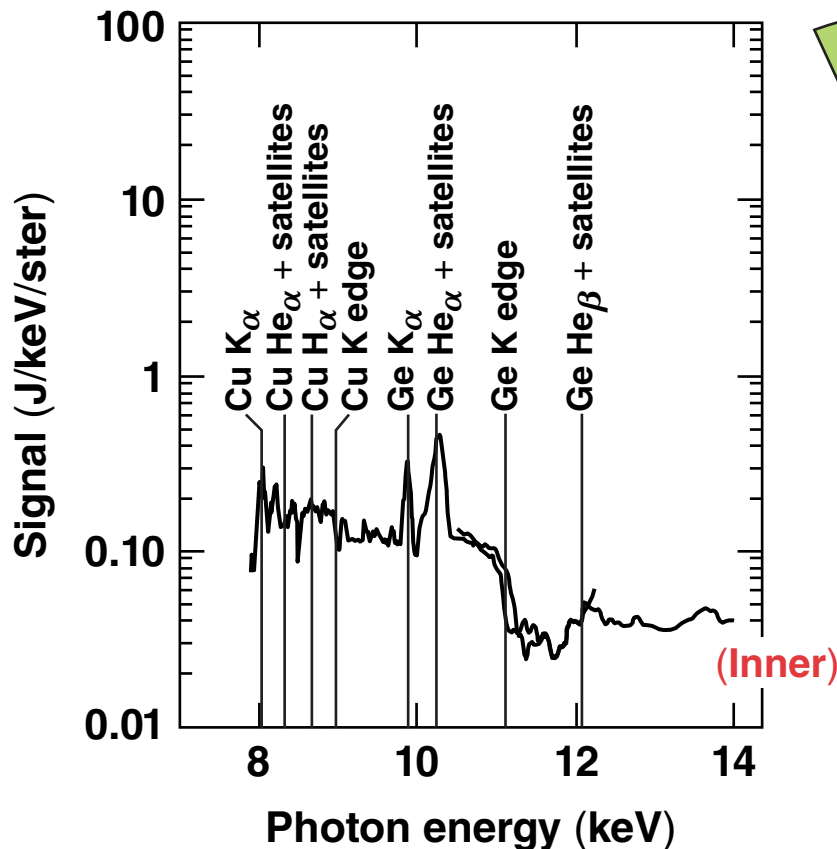
¹PO4.00009, this conference

²LLE Summer High School Research Program

³CP8.00069, this conference

Mix mass is modeled as multiple spheres of ablator mass with uniform plasma conditions and areal density

Cu, Ge, Si-doped CH ablator



Hot-spot mix-mass analysis assumes:

- 250-ps emission
- The original shell dopant concentration
- Shell transmission based on simulations

| Layer | Dopant (atm. %) |
|-------|-------------------------|
| 1 | Cu (0.1%) |
| 2 | Si (0.7%) Ge (0.15%) |
| 3 | Si (1.7%) Ge (0.15%) |
| 4 | Si (1%) |
| 5 | None |

Atomic model fit gives estimates of:

T , ρ , and ρR

(Outer)

Mix mass is estimated from the absolute brightness of the Ge He $_{\alpha}$ line satellites*



- The total Ge ion number is obtained from the total He $_{\alpha}$ satellite line emission and a PrismSPECT** model of the line intensity per Ge ion
- Modeling includes term-split spectral detail, accurate line profiles,† and radiation-kinetic coupling for a sphere of areal density ρR and mass $m = 4\pi(\rho R)^3/(3\rho^2)$
- The Ge concentration and ion number give the total mix mass M
- With a number of spheres $N = M/m$ occupying a fraction f of the hot-spot volume, the probability that an escaping dopant photon will encounter a second sphere is $N^{1/3} f^{2/3} \sim 0.1$. Therefore,

the shell-material spheres radiate independently.

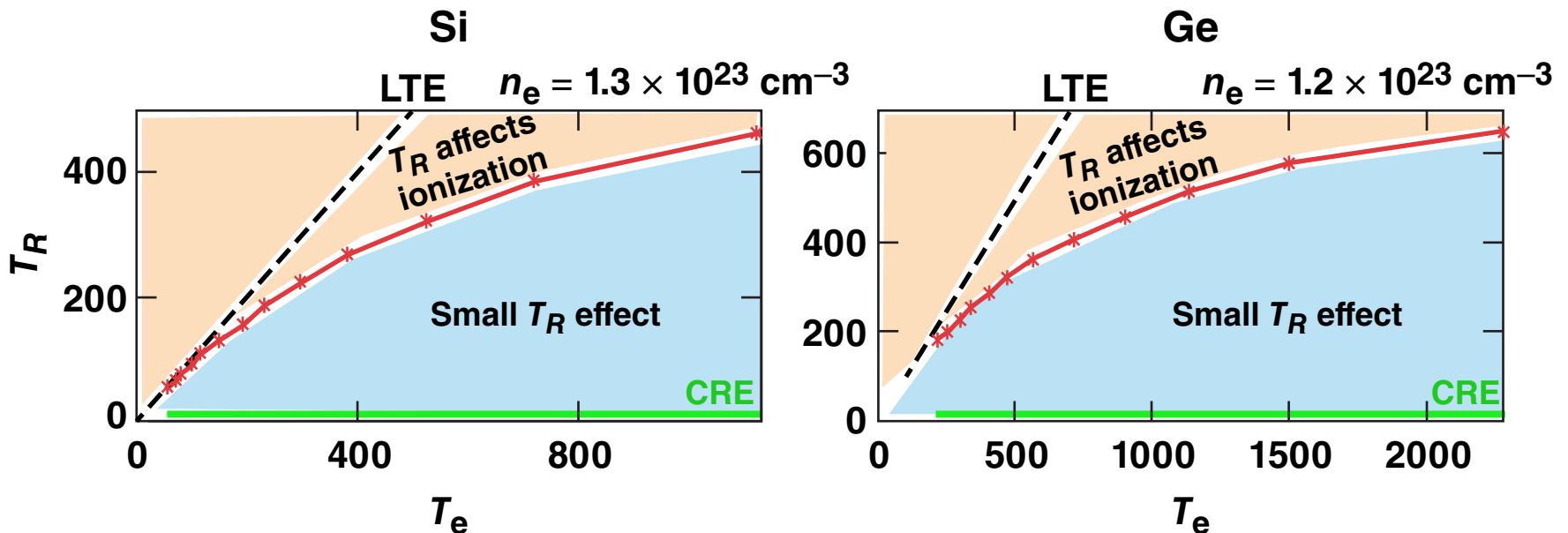
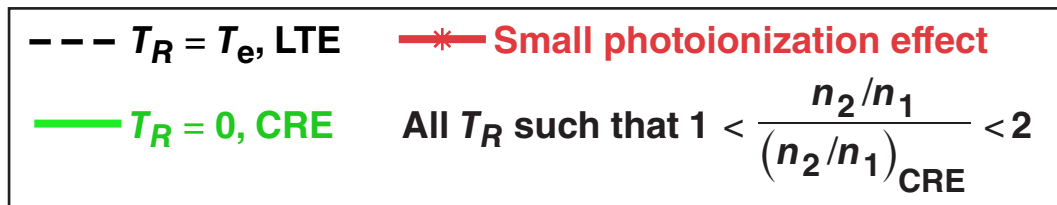
*S. P. Regan *et al.*, Phys Plasmas 19, 056307 (2012).

**J.J. MacFarlane *et al.*, High Energy Density Phys. 3, 181 (2006).

†R. C. Mancini *et al.*, Comput. Phys. Commun. 63, 314 (1991).

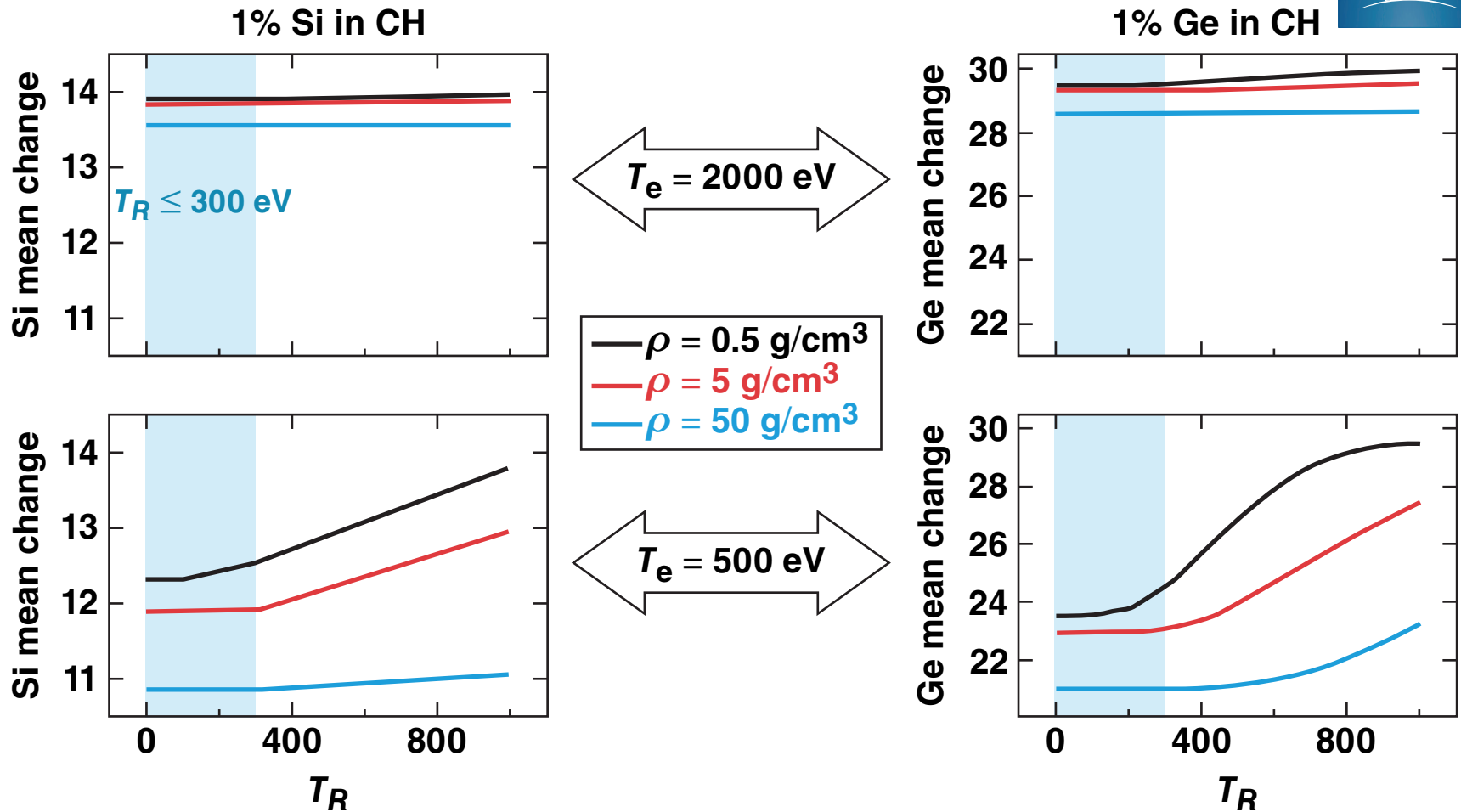
A T_R -modified Saha equation estimates the effect of external radiation on the ionization state of additive ions

$$\frac{n_2}{n_1} = \frac{n_e C_{12}(T_e) + R_{12}(T_e, T_R)}{n_e^2 C_{21}(T_e) + n_e [R_{21}^{\text{spontaneous}}(T_e) + R_{21}^{\text{stimulated}}(T_e, T_R)]}$$

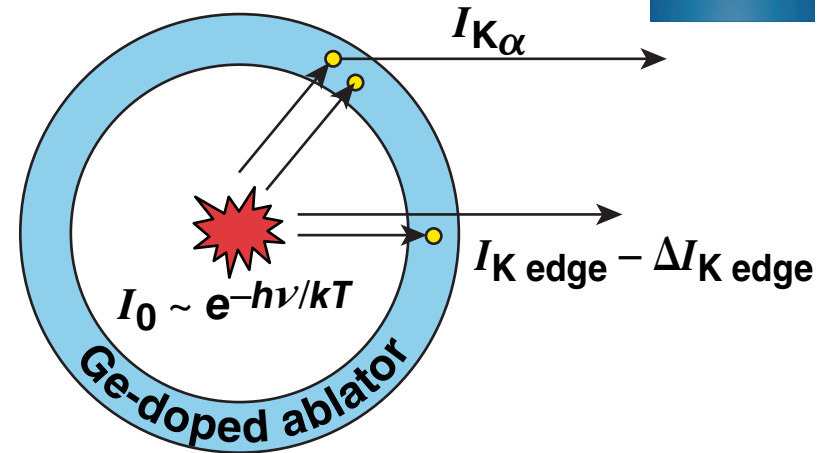
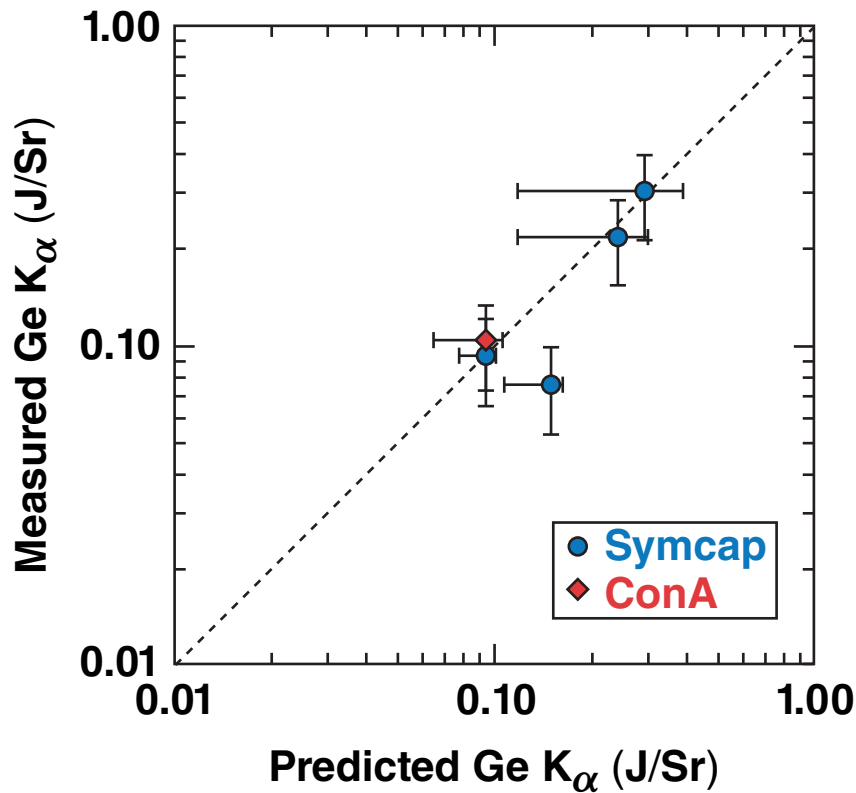


A radiation temperature of $T_R < 300$ eV does not substantially change the ionization of dopants at T_e above ~ 500 eV

PrismSPECT* results



The measured K_α emission is consistent with the K-shell absorption of the core continuum*



$$\frac{\int I_{K_\alpha} \frac{d h \nu}{h \nu}}{\int \Delta I_{K \text{ edge}} \frac{d h \nu}{h \nu}} \sim \omega_{K_\alpha}$$

$$\mu_K \rho_{\text{Ge}} R = \ln \left[\frac{I_{K \text{ edge}}}{I_{K \text{ edge}} - \Delta I_{K \text{ edge}}} \right]$$

Ge fluorescence efficiency: $\omega_{K_\alpha} = 0.539^{**}$

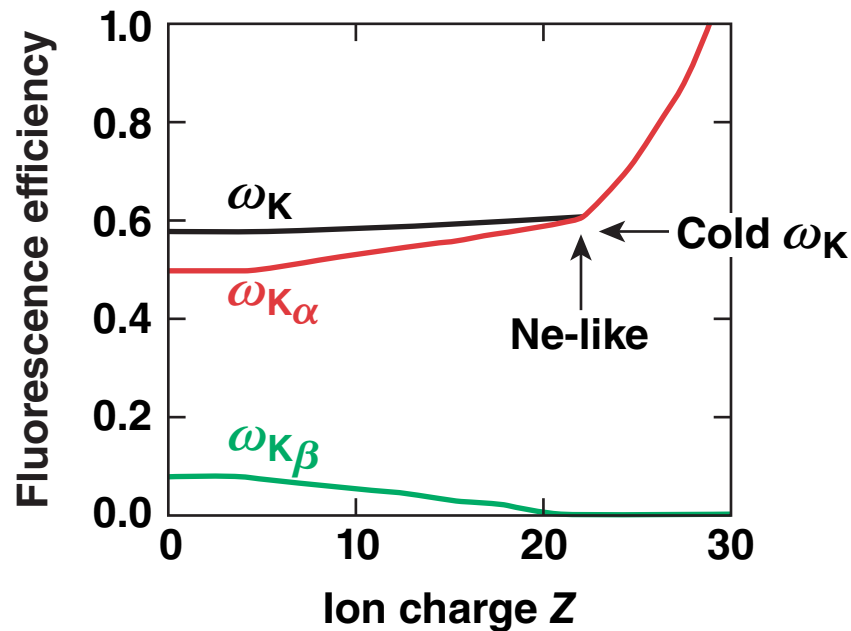
*S. P. Regan et al., Phys Plasmas **19**, 056307 (2012).

J. Hubbell et al., J. Phys. Chem. Ref. Data **23, 339 (1994).

The cold ω_K is a good approximation for the Ge K_α fluorescence efficiency for ionization below Ne-like

From level population (P_L, P_M) scaling:*

$$\omega_K = \frac{[A_\alpha P_L + A_\beta P_M]}{[A_\alpha P_L + A_\beta P_M] + [A_{K,LL} P_L^2 + A_{K,LM} P_L P_M + \text{etc.}]}$$



Emission: A_α, A_β
Autoionization: $A_{K,LL}, A_{K,LM}$

$$\frac{\omega_{K\beta}}{\omega_{K\alpha}} = \frac{A_\beta P_M}{A_\alpha P_L}$$

* E. J. McGuire, Phys. Rev. 185, 1 (1969);
E. J. McGuire, Phys. Rev. A 2, 273 (1970).

Free-electron effects alter the isolated-atom K_α fluorescence efficiency of Ge and Cu only slightly



- Collisional decay (C_α), recombination ($C_{R,K}$), and radiative recombination ($R_{R,K}$) compete with autoionization and K_α emission and reduce the isolated-atom value of $\omega_{K_\alpha}^*$

$$\omega_{K_\alpha}^{\text{corrected}} = \frac{A_\alpha}{A_\alpha + A_{\text{auto}} + C_\alpha + C_{R,K} + R_{R,K}} = \frac{\omega_{K_\alpha}}{1 + (C_\alpha + C_{R,K} + R_{R,K})(\omega_{K_\alpha}/A_\alpha)}$$

Correction terms for $n_e = 10^{25} \text{ cm}^{-3}$ and $kT_e = 100 \text{ eV}$:

$$\omega_{K_\alpha} C_\alpha / A_\alpha \leq 5.9 \times 10^{-2}$$

$$\omega_{K_\alpha} C_{R,K} / A_\alpha \leq 9.2 \times 10^{-4}$$

$$\omega_{K_\alpha} R_{R,K} / A_\alpha \leq 3.1 \times 10^{-2}$$

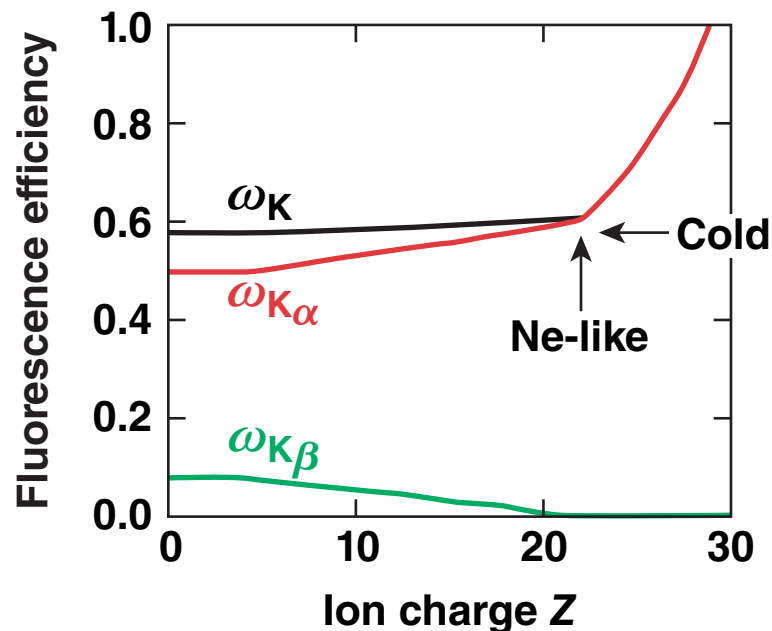
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$$\frac{\omega_{K\beta}}{\omega_{K\alpha}} = \frac{A_\beta P_M}{A_\alpha P_L}$$

For Ge:**

$$\begin{aligned} A_{K,LL} &= 1.08 \times 10^{15} \text{ sec}^{-1} \\ A_{K,LM} &= 2.90 \times 10^{14} \text{ sec}^{-1} \\ A_\alpha &= 1.65 \times 10^{15} \text{ sec}^{-1} \\ A_\beta &= 2.64 \times 10^{14} \text{ sec}^{-1} \\ A_{K,LL}, \text{ etc., } &\dots \end{aligned}$$

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$$\omega_{K_\alpha} C_\alpha / A_\alpha = 5.9 \times 10^{-3} \frac{\left(\frac{\omega_{K_\alpha}}{0.54}\right) \left(\frac{\eta_e}{10^{24}}\right)}{\left(\frac{h\nu_\alpha}{9.8 \text{ keV}}\right)^3 \left(\frac{kT}{0.1 \text{ keV}}\right)^{1/2}}$$

$$\omega_{K_\alpha} C_{R,K} / A_\alpha = 9.2 \times 10^{-6} \frac{\left(\frac{\omega_{K_\alpha}}{0.54}\right) \left(\frac{\eta_e}{10^{24}}\right)^2}{\left(\frac{h\nu_\alpha}{9.8 \text{ keV}}\right)^3 \left(\frac{kT}{0.1 \text{ keV}}\right)}$$

$$\omega_{K_\alpha} R_{R,K} / A_\alpha = 3.1 \times 10^{-3} \frac{\left(\frac{\omega_{K_\alpha}}{0.54}\right) \left(\frac{\eta_e}{10^{24}}\right)}{\left(\frac{h\nu_\alpha}{9.8 \text{ keV}}\right)^{3/2} \left(\frac{kT}{0.1 \text{ keV}}\right)^{1/2}}$$